



#8/Amndt
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S/N 08/903,486

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Leonard Forbes et al.

Examiner: W. Mintel

Serial No.: 08/903,486

Group Art Unit: 2811

Filed: July 29, 1997

Docket: 303.326US1

Title: SILICON CARBIDE GATE TRANSISTOR AND FABRICATION PROCESS

AMENDMENT AND RESPONSE

Assistant Commissioner for Patents
Washington, D.C. 20231

In response to the Office Action mailed April 15, 1999, please amend the above-identified patent application as follows.

IN THE TITLE

Please delete the title and replace it with --SILICON CARBIDE GATE TRANSISTOR--.

IN THE SPECIFICATION

Page 1, line 14: after "As" please insert --is--.

Page 1, line 19: change "affects" to --affect--.

Page 5, line 11: after "having" insert --a--.

Page 5, line 21: change "enables" to --enable--.

Page 6, line 1: change "application serial number 08/790,603" to --number 5,801,401, issued September 1, 1998, and--.

Page 6, line 10: delete "regions of".

Page 6, line 17: change "Si_xC_{1-x}" to --Si_{1-x}C_x--.

Page 7, line 5: change "is," to --is--.

Page 7, line 7: change "112" to --112,--.

Page 10, line 20: after "though" delete "it".

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02 FC:103 2.00 CH
03 FC:102 144.00 OP
76.00 OP